

# United States Patent and Trademark Office

UNITED STATES DEPARTMENT OF COMMERCE United States Patent and Trademark Office Address: COMMISSIONER FOR PATENTS P.O. Box 1450 Alexandria, Virginia 22313-1450 www.uspto.gov

APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
10/026,019	12/20/2001	Ralph H. Johnson	15436.436.3	6105
	12/20/2001 Ralph H. Johnson  7590 09/04/2007 N NYDEGGER  DUTH TEMPLE E GATE TOWER	EXAMINER		
60 EAST SOU'	TH TEMPLE		NGUYEN,	DUNG T
1000 EAGLE GATE TOWER SALT LAKE CITY, UT 84111			ART UNIT	PAPER NUMBER
	,		2828	
			MAIL DATE	DELIVERY MODE
			09/04/2007	PAPER

Please find below and/or attached an Office communication concerning this application or proceeding.

The time period for reply, if any, is set in the attached communication.

		TH	
	Application No.	Applicant(s)	
	10/026,019	JOHNSON, RALPH H.	
Office Action Summary	Examiner	Art Unit	
	Dung (Michael) T. Nguyen	2828	
The MAILING DATE of this communicatio Period for Reply	n appears on the cover sheet with the	he correspondence address	
• •	SEDI VIC CET TO EVOIDE AMONG	THE OF THE TY (20) FAVO	
A SHORTENED STATUTORY PERIOD FOR R WHICHEVER IS LONGER, FROM THE MAILIN  - Extensions of time may be available under the provisions of 37 C after SIX (6) MONTHS from the mailing date of this communicatic  - If NO period for reply is specified above, the maximum statutory p  - Failure to reply within the set or extended period for reply will, by Any reply received by the Office later than three months after the earned patent term adjustment. See 37 CFR 1.704(b).	IG DATE OF THIS COMMUNICAT FR 1.136(a). In no event, however, may a reply to on. period will apply and will expire SIX (6) MONTHS statute, cause the application to become ABAND	TION. De timely filed  from the mailing date of this communication.  ONED (35 U.S.C. § 133).	
Status		,	
1) Responsive to communication(s) filed on	20 June 2007.		
	This action is non-final.		
3) Since this application is in condition for al	lowance except for formal matters,	prosecution as to the merits is	
closed in accordance with the practice un	der <i>Ex parte Quayle</i> , 1935 C.D. 11	, 453 O.G. 213.	
Disposition of Claims	,		
4) Claim(s) 2,3,5-7,9,14-16,18,21-30,33 and	/ 34 is/are pending in the application	n	
4a) Of the above claim(s) is/are wit			
5)⊠ Claim(s) <u>14,24-30 and 33</u> is/are allowed.			
6) Claim(s) 2,5-7,15,21,23 and 34 is/are reje	ected.		
7) Claim(s) 3,9,16,18 and 22 is/are objected	to.		
8) Claim(s) are subject to restriction a	and/or election requirement.		
Application Papers			
9)☐ The specification is objected to by the Exa	miner		
10) The drawing(s) filed on is/are: a)		he Examiner.	
Applicant may not request that any objection to	•		
Replacement drawing sheet(s) including the co	orrection is required if the drawing(s) is	s objected to. See 37 CFR 1.121(d).	
11)☐ The oath or declaration is objected to by the	ne Examiner. Note the attached Off	fice Action or form PTO-152.	
Priority under 35 U.S.C. § 119			
12) ☐ Acknowledgment is made of a claim for for	reign priority under 35 U.S.C. & 119	9(a)-(d) or (f)	
a) ☐ All b) ☐ Some * c) ☐ None of:	g., priority under 00 0.0.0. g 113	عرض رض کا رای	
1.☐ Certified copies of the priority docur	ments have been received.		
2 Certified copies of the priority docur		cation No	
3. Copies of the certified copies of the	priority documents have been rece	eived in this National Stage	
application from the International Br	ureau (PCT Ruļe 17.2(a)).	•	
* See the attached detailed Office action for a	a list of the certified copies not rece	eived.	
	•		
Attachment(s)	_		
Notice of References Cited (PTO-892)	4) Interview Summ 8) Paper No(s)/Ma		
<ul> <li>P) Notice of Draftsperson's Patent Drawing Review (PTO-94)</li> <li>D) Information Disclosure Statement(s) (PTO/SB/08)</li> </ul>		nal Patent Application	
Paper No(s)/Mail Date	6) Other:		

Application/Control Number: 10/026,019

Art Unit: 2828

#### OFFICE ACTION

The indicated allowed claims 21-23 are withdrawn due to the newly found prior art.

### Claim Rejections - 35 USC § 102

The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless –

(e) the invention was described in (1) an application for patent, published under section 122(b), by another filed in the United States before the invention by the applicant for patent or (2) a patent granted on an application for patent by another filed in the United States before the invention by the applicant for patent, except that an international application filed under the treaty defined in section 351(a) shall have the effects for purposes of this subsection of an application filed in the United States only if the international application designated the United States and was published under Article 21(2) of such treaty in the English language.

Claims 2, 5-7, 15, 21, 23, and 34 are rejected under 35 U.S.C. 102(e) as being anticipated by Tsuda et al. (6399966).

Claims 21 and 23, Fig.6, Table 1, and col.11, l.21-22 disclose an active region 406 comprising at least one quantum well with a thickness comprised of InGaAsN and including A1GaAs barrier layers sandwiching said at least one quantum well; and confinement layers 404 & 409 sandwiching said active region.

Claims 5-7, 34, Fig.6, Table 1, and col.11, 1.21-22 disclose

an active region 406 further comprising at least one quantum well with a thickness and including barrier layers sandwiching said at least one quantum well, at least one of the quantum well and the barrier layers including nitrogen, wherein said at least one quantum well is further comprised of Sb;

upper and lower confinement layers 404 & 409 sandwiching said active region, wherein the barrier layers and/or the upper and lower confinement layers are comprised of material that

reduces a level of non-confining valence band discontinuity in the quantum well due to the presence of nitrogen in the quantum well (since Table 1 shows the presence of nitrogen in the QW, it is understood that the barrier layers and/or the upper and lower confinement layers must be comprised of material that reduces a level of non-confining valence band discontinuity in the quantum well due to the presence of nitrogen in the quantum well. Otherwise, the laser device would not work properly); and

a flattening layer 405 interposed between the lower confinement layer and the at least one quantum well.

Claim 2, Table 1 shows GaAsN barrier layers.

Claim 15, Table 1 shows InGaAs barrier layers.

#### Allowable Subject Matter

Claims 3, 9, 16, 18, and 22 are objected to as being dependent upon a rejected base claim, but would be allowable if rewritten in independent form including all of the limitations of the base claim and any intervening claims.

Claims 14, 24-30, and 33 are allowed.

Art Unit: 2828

## **Communication Information**

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Dung (Michael) T Nguyen whose telephone number is (571) 272-1949. The examiner can normally be reached on 8:30 - 17:00.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Min Harvey can be reached on (571) 272-1835. The fax phone number for the organization where this application or proceeding is assigned is (703) 872-9306.

Any inquiry of a general nature or relating to the status of this application or proceeding should be directed to the receptionist whose telephone number is (703) 306-3329.

Michael Dung Nguyen

8/24/07

Juny m

**Primary Examiner**